

EL5150, EL5151, EL5250, EL5251, EL5451

PRELIMINARY

Data Sheet

February 26, 2004

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FN7384.1
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200MHz Amplifiers



The EL5150, EL5151, EL5250, EL5251, and EL5451 are 200MHz bandwidth -3dB voltage mode

feedback amplifiers with DC accuracy of 0.01%, 1mV offsets and 10kV/V open loop gains. These amplifiers are ideally suited for applications ranging from precision measurement instrumentation to high speed video and monitor applications. Capable of operating with as little as 1.4mA of current from a single supply ranging from 5V to 12V dual supplies ranging from $\pm 2.5V$ to $\pm 5.0V$, these amplifiers are also well suited for handheld, portable and battery-powered equipment.

Single amplifiers are offered in SOT-23 packages and duals in a 10-pin MSOP package for applications where board space is critical. Quad amplifiers are available in a 14-pin SO package. Additionally, singles and duals are available in the industry-standard 8-pin SO package. All parts operate over the industrial temperature range of -40°C to +85°C.

PART NUMBER	PACKAGE	TAPE & REEL	PKG. DWG. #
EL5150IS	8-Pin SO	-	MDP0027
EL5150IS-T7	8-Pin SO	7"	MDP0027
EL5150IS-T13	8-Pin SO	13"	MDP0027
EL5150IW-T7	6-Pin SOT-23	7" (3K pcs)	MDP0038
EL5150IW-T7A	6-Pin SOT-23	7" (250 pcs)	MDP0038
EL5151IW-T7	5-Pin SOT-23	7" (3K pcs)	MDP0038
EL5151IW-T7A	5-Pin SOT-23	7" (250 pcs)	MDP0038
EL5250IY	10-Pin MSOP	-	MDP0043
EL5250IY-T7	10-Pin MSOP	7"	MDP0043
EL5250IY-T13	10-Pin MSOP	13"	MDP0043
EL5251IS	8-Pin SO	-	MDP0027
EL5251IS-T7	8-Pin SO	7"	MDP0027
EL5251IS-T13	8-Pin SO	13"	MDP0027
EL5251IY	8-Pin MSOP	-	MDP0043
EL5251IY-T7	8-Pin MSOP	7"	MDP0043
EL5251IY-T13	8-Pin MSOP	13"	MDP0043
EL5451IS	14-Pin SO	-	MDP0027
EL5451IS-T7	14-Pin SO	7"	MDP0027
EL5451IS-T13	14-Pin SO	13"	MDP0027

Ordering Information

Features

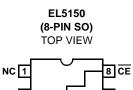
- 200MHz -3dB bandwidth
- 110V/µs slew rate
- Very high open loop gains 50kV/V
- Low supply current = 1.4mA
- Single supplies from 5V to 12V
- Dual supplies from ±2.5V to ±5V
- Fast disable on the EL5150 and EL5250
- Low cost

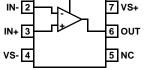
Applications

- Imaging
- Instrumentation
- Video
- · Communications devices

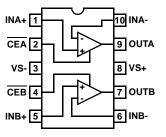
EL5150

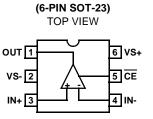




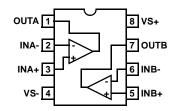


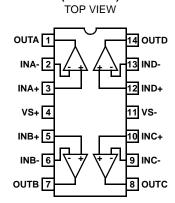






EL5251 (8-PIN MSOP) TOP VIEW





EL5451

(14-PIN SO)

EL5151

(5-PIN SOT-23)

TOP VIEW

5 VS+

4 IN-

OUT 1

VS- 2

IN+ 3



Absolute Maximum Ratings (T_A = 25°C)

Supply Voltage between V _S and GND	Juncti
Maximum Continuous Output Current	Storag
Pin VoltagesGND -0.5V to V _S +0.5V	Ambie
Power Dissipation See Curves	Curre

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed. Typical values are for information purposes only. Unless otherwise noted, all tests are at the specified temperature and are pulsed tests, therefore: $T_J = T_C = T_A$

Electrical Specifications V_{S} + = +5V, V_{S} - = ±5V, R_{L} = 150 Ω , T_{A} = 25°C, unless otherwise specified.

PARAMETER	DESCRIPTION	CONDITIONS	MIN	TYP	MAX	UNIT
AC PERFORM	ANCE		+			
BW	-3dB Bandwidth	$A_V = +1, R_L = 500\Omega$		200		MHz
		$A_V = +2, R_L = 150\Omega$		36		MHz
GBWP	Gain Bandwidth Product	A _V = 500		86		MHz
BW1	0.1dB Bandwidth	$A_{V} = +1, R_{L} = 500\Omega$		10		MHz
SR SI	Slew Rate	$V_{O} = \pm 2.5 V, A_{V} = \pm 2$	50	67		V/µs
		$V_{O} = \pm 3.0V, A_{V} = 1, R_{L} = 500\Omega$		100		V/µs
t _S	0.1% Settling Time	$V_{OUT} = -1V$ to +1V, $A_V = -2$		80		ns
dG	Differential Gain Error (Note 1)	$A_V = +2, R_L = 150\Omega$		0.1		%
dP	Differential Phase Error (Note 1)	$A_V = +2, R_L = 150\Omega$		1.17		o
V _N	Input Referred Voltage Noise			12		nV/√Hz
I _N	Input Referred Current Noise			1.6		pA/√Hz
DC PERFORM	ANCE			•		•
V _{OS}	Offset Voltage		-1	0.5	1	mV
T _C V _{OS}	Input Offset Voltage Temperature Coefficient	Measured from T_{MIN} to T_{MAX}		-2		µV/°C
A _{VOL}	Open Loop Gain		15	56		kV/V
INPUT CHARA	CTERISTICS		L		1	1
CMIR	Common Mode Input Range	Guaranteed by CMRR test	TBD		TBD	V
CMRR	Common Mode Rejection Ratio		85	100		dB
IB	Input Bias Current		-100	20	+100	mA
I _{OS}	Input Offset Current		-30	6	30	nA
R _{IN}	Input Resistance		80	170		MΩ
C _{IN}	Input Capacitance			1		pF
OUTPUT CHAF	RACTERISTICS		<u> </u>			
V _{OUT}	Output Voltage Swing Low	$R_L = 150\Omega$ to GND	±2.5	±2.8		V
		$R_L = 500\Omega$ to GND	±3.1	±3.4		V
IOUT	Output Current	$R_L = 10\Omega$ to GND	±40	±70		mA
ENABLE (SELE	ECTED PACKAGES ONLY)		1		1	1
t _{EN}	Enable Time			170		ns
tDIS	Disable Time			1.25		μs
I _{IHCE}	CE Pin Input High Current	CE = V _S +		0	-1	μA

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DESCRIPTION	CONDITIONS	MIN	TYP	MAX	UNIT
CE Pin Input Low Current	CE = V _S -	5	13	25	μA
CE Input High Voltage for Power-down		V _S + -1			V
CE Input Low Voltage for Power-down				V _S + -3	V
Supply Current - Enabled (per amplifier)	No load, $V_{IN} = 0V$, CE = +5V	1.12	1.35	1.6	mA
Supply Current - Disabled	No load, V _{IN} = 0V	5	13	25	μA
Power Supply Rejection Ratio	DC, $V_{S} = \pm 3.0V$ to $\pm 6.0V$	80	110		dB
-	CE Pin Input Low Current CE Input High Voltage for Power-down CE Input Low Voltage for Power-down Supply Current - Enabled (per amplifier) Supply Current - Disabled	CE Pin Input Low Current CE CE Input High Voltage for Power-down CE Input Low Voltage for Power-down Supply Current - Enabled (per amplifier) No load, V _{IN} = 0V, CE = +5V Supply Current - Disabled No load, V _{IN} = 0V	\overline{CE} Pin Input Low Current $\overline{CE} = V_S$ - 5 \overline{CE} Input High Voltage for Power-down V_S + -1 \overline{CE} Input Low Voltage for Power-down V Supply Current - Enabled (per amplifier) No load, $V_{IN} = 0V$, $CE = +5V$ 1.12 Supply Current - Disabled No load, $V_{IN} = 0V$ 5	\overline{CE} Pin Input Low Current $\overline{CE} = V_S^-$ 5 13 \overline{CE} Input High Voltage for Power-down $V_S^+ - 1$ $V_S^+ - 1$ \overline{CE} Input Low Voltage for Power-down Image: Note that the second seco	\overline{CE} Pin Input Low Current $\overline{CE} = V_{S}$ -51325 \overline{CE} Input High Voltage for Power-down V_{S} + -1 V_{S} + -1 V_{S} + -3 \overline{CE} Input Low Voltage for Power-down V_{S} + -3 V_{S} + -3Supply Current - Enabled (per amplifier)No load, V_{IN} = 0V, CE = +5V1.121.351.6Supply Current - DisabledNo load, V_{IN} = 0V51325

Electrical Specifications V_{S} + = +5V, V_{S} - = ±5V, R_{L} = 150 Ω , T_{A} = 25°C, unless otherwise specified. (Continued)

NOTE:

1. Standard NTSC test, AC signal amplitude = $286mV_{P-P}$, f = 3.58MHz, V_{OUT} is swept from 0.8V to 3.4V, R_L is DC coupled

Typical Performance Curves

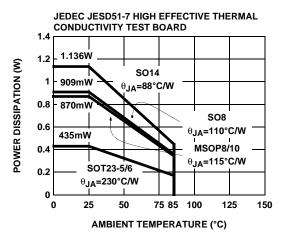
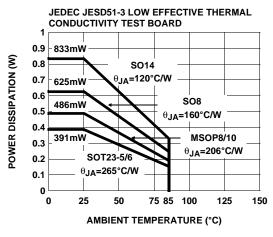


FIGURE 1. PACKAGE POWER DISSIPATION vs AMBIENT TEMPERATURE





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